

# MSD1819A-RT1G, NSVMSD1819A-RT1G

## General Purpose Amplifier Transistor

### NPN Silicon Surface Mount

This NPN Silicon Epitaxial Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

#### Features

- High  $h_{FE}$ , 210–460
- Low  $V_{CE(sat)}$ , < 0.5 V
- Moisture Sensitivity Level 1
- ESD Protection:
  - ◆ Human Body Model > 4000 V
  - ◆ Machine Model > 400 V
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{(BR)CBO}$	60	Vdc
Collector-Emitter Voltage	$V_{(BR)CEO}$	50	Vdc
Emitter-Base Voltage	$V_{(BR)EBO}$	7.0	Vdc
Collector Current – Continuous	$I_C$	100	mA <sub>dc</sub>
Collector Current – Peak	$I_{C(P)}$	200	mA <sub>dc</sub>

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 1)	$P_D$	150	mW
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$

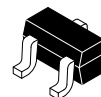
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

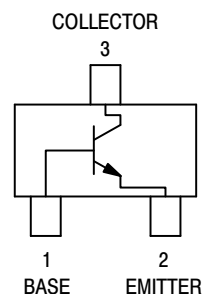


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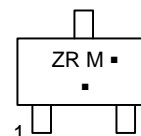
[www.onsemi.com](http://www.onsemi.com)



SC-70 (SOT-323)  
CASE 419  
STYLE 3



#### MARKING DIAGRAM



ZR = Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping†
MSD1819A-RT1G	SC-70 (Pb-Free)	3,000 / Tape & Reel
NSVMSD1819A-RT1G	SC-70 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

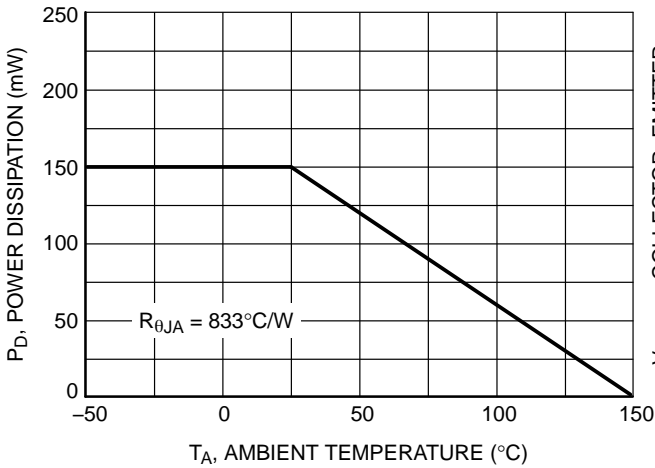
# MSD1819A-RT1G, NSVMSD1819A-RT1G

## ELECTRICAL CHARACTERISTICS

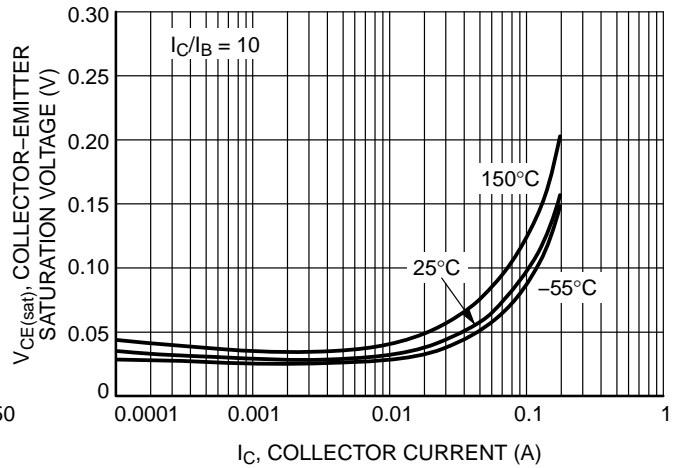
Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage ( $I_C = 2.0 \text{ mAdc}$ , $I_B = 0$ )	$V_{(BR)CEO}$	50	–	Vdc
Collector-Base Breakdown Voltage ( $I_C = 10 \text{ } \mu\text{Adc}$ , $I_E = 0$ )	$V_{(BR)CBO}$	60	–	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \text{ } \mu\text{Adc}$ , $I_C = 0$ )	$V_{(BR)EBO}$	7.0	–	Vdc
Collector-Base Cutoff Current ( $V_{CB} = 20 \text{ Vdc}$ , $I_E = 0$ )	$I_{CBO}$	–	0.1	$\mu\text{A}$
Collector-Emitter Cutoff Current ( $V_{CE} = 10 \text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	–	0.1	$\mu\text{A}$
DC Current Gain (Note 2) ( $V_{CE} = 10 \text{ Vdc}$ , $I_C = 2.0 \text{ mAdc}$ ) ( $V_{CE} = 2.0 \text{ Vdc}$ , $I_C = 100 \text{ mAdc}$ )	$h_{FE1}$ $h_{FE2}$	210 90	340 –	–
Collector-Emitter Saturation Voltage (Note 2) ( $I_C = 100 \text{ mAdc}$ , $I_B = 10 \text{ mAdc}$ )	$V_{CE(sat)}$	–	0.5	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

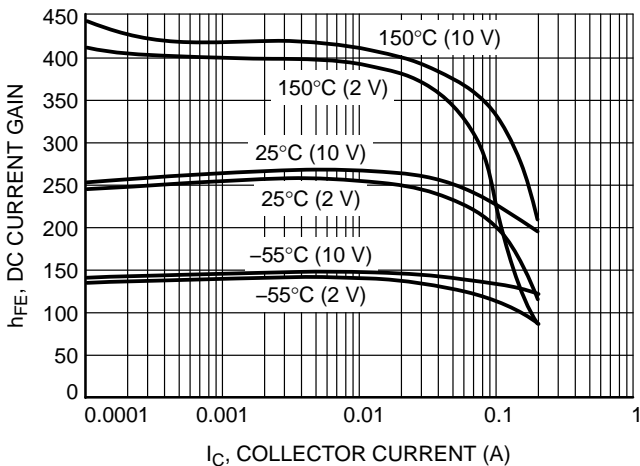
2. Pulse Test: Pulse Width  $\leq 300 \text{ } \mu\text{s}$ , D.C.  $\leq 2\%$ .



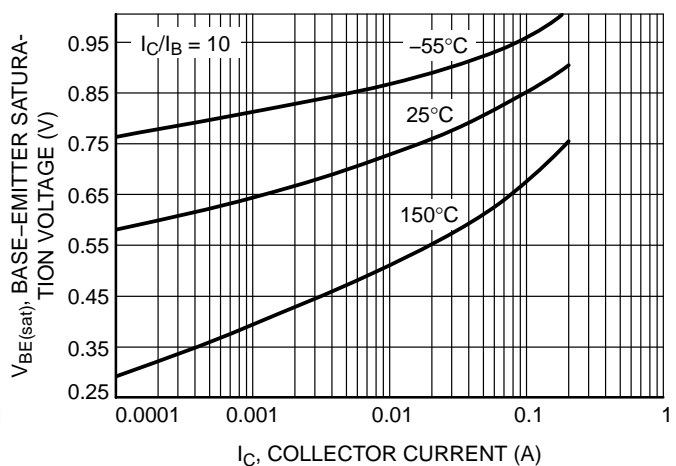
**Figure 1. Derating Curve**



**Figure 2. Collector Emitter Saturation Voltage vs. Collector Current**

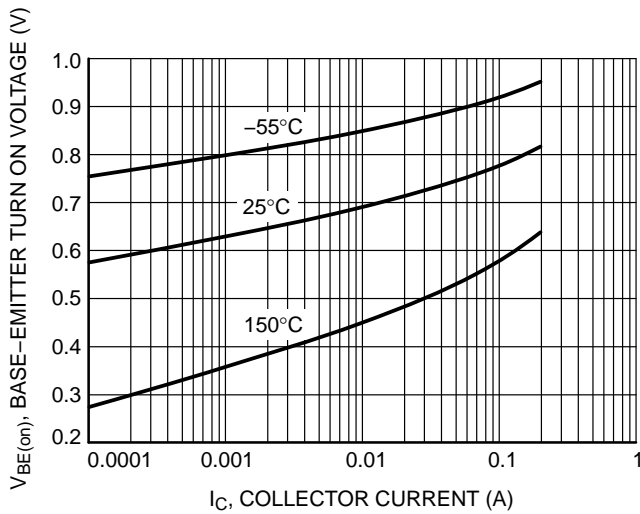


**Figure 3. DC Current Gain vs. Collector Current**

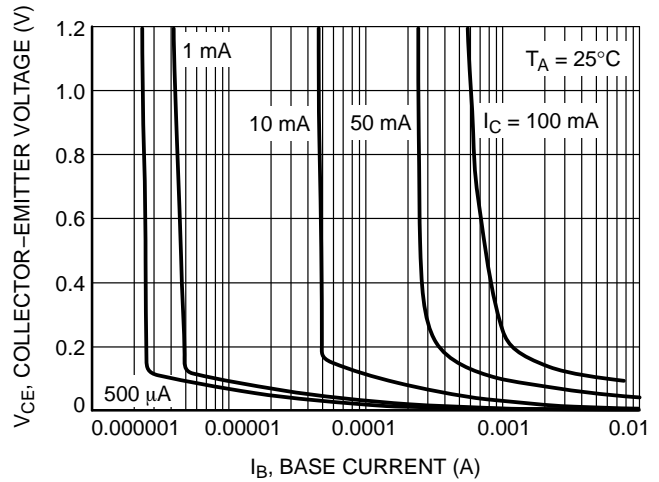


**Figure 4. Base Emitter Saturation Voltage vs. Collector Current**

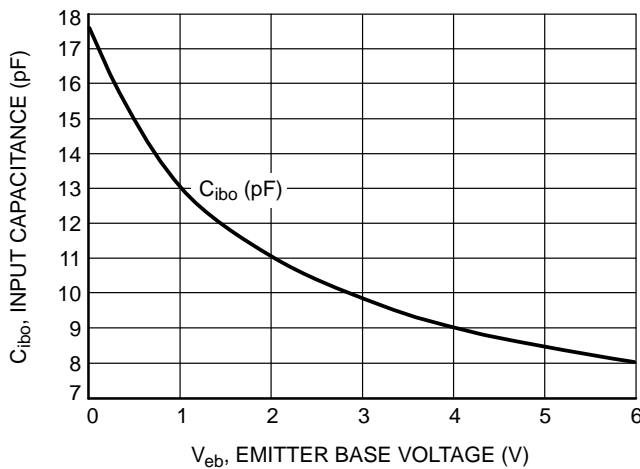
# MSD1819A-RT1G, NSVMSD1819A-RT1G



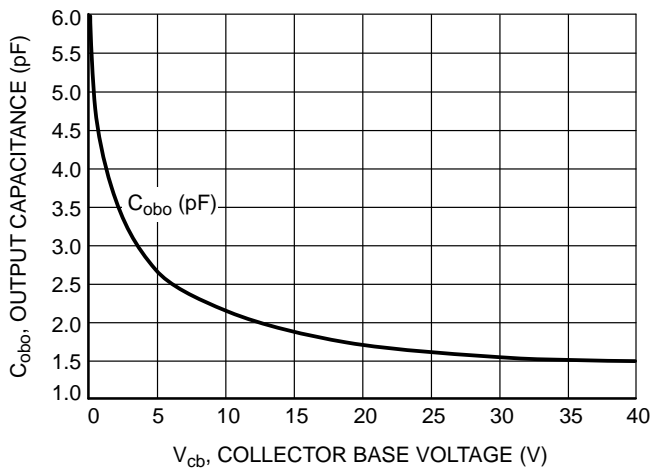
**Figure 5. Base-Emitter Turn-On Voltage vs. Collector Current**



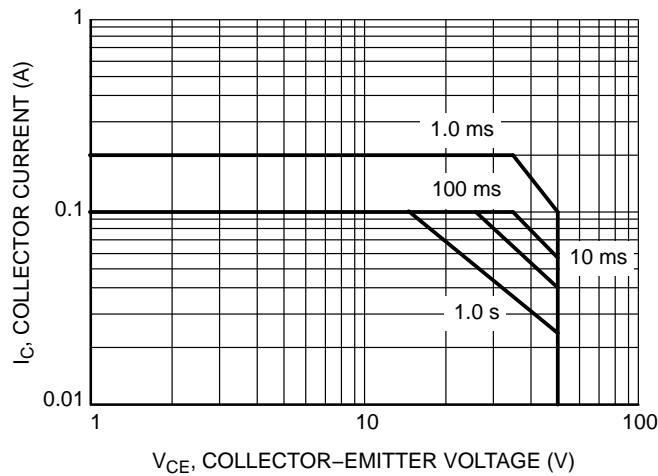
**Figure 6. Collector Saturation Region**



**Figure 7. Input Capacitance**



**Figure 8. Output Capacitance**



**Figure 9. Safe Operating Area**

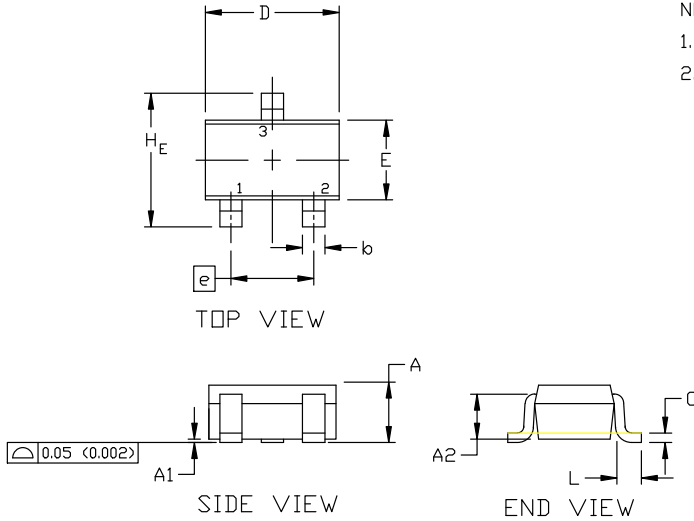
# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



SCALE 4:1

## SC-70 (SOT-323) CASE 419 ISSUE R

DATE 11 OCT 2022

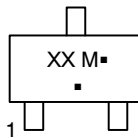


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH

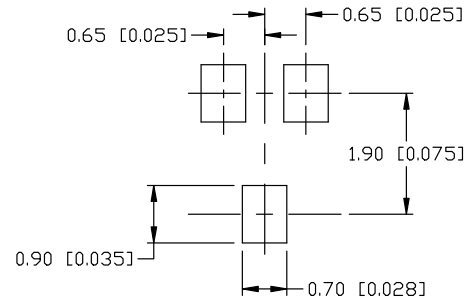
DIM	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 BSC		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.00	2.20	0.071	0.080	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
H <sub>E</sub>	2.00	2.10	2.40	0.079	0.083	0.095

### GENERIC MARKING DIAGRAM



- XX = Specific Device Code
- M = Date Code
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.



\* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

### SOLDERING FOOTPRINT

STYLE 1: CANCELLED	STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE	STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE	
STYLE 6: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 7: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 8: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 9: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE	STYLE 10: PIN 1. CATHODE 2. ANODE 3. ANODE-CATHODE	STYLE 11: PIN 1. CATHODE 2. CATHODE 3. CATHODE

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<b>DESCRIPTION:</b>	<b>SC-70 (SOT-323)</b>	<b>PAGE 1 OF 1</b>

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